## NSN 5961-01-379-7298

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Current Rating Per Characteristic:
600.00 milliamperes source cutoff current
Power Rating Per Characteristic:
3.0 watts small-signal input power, common-collector preset
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0